PCN Num		nber:	20150915001								PCN Date: 09/21/2		2015	
Title:		Qualifica	cation of 100% Cu wire bonding on select nfBGA Devices											
Cus	stome	er Conta	ct:	PCN N	Nanage	<u>r</u>	Dept:	Quality	Services					
Proposed 1 st Ship				te:	e: 12/21/20		15	Estimated			-		•	
Cha	Change Type: Availability: sample request							.50						
		mbly Sit	e	2			Design				Wafer Bump Site			
\boxtimes	Asse	mbly Pro	cess	iess			Data Sheet				Wafer Bump Material			al
\boxtimes		mbly Ma	terials				Part number change				Wafer Bump Process			
			Specification				Test Site				Wafer Fab Site			
	Pack	ing/Ship	hipping/Labeling				Test Process				Wafer Fab Materials			5
											Wafe	r Fab I	Process	
PCN Details														
		ion of C												
			•	leased	to an	nour	nce the c	lualificati	on of 100%	% Cι	ı bondi	ng for	the nfB	GA
aev	ices li	sted belo	ow.											
			Wha	t		Cur	rrent Bonding		Nou	lew Bonding				
		55.00		d Pade	5		Cu, 0.8 r	-	Cu, 0.70 mil					
									Cu, 0.70 mil					
45um Bond Pa				u rau:	5	Au, 0.8 mil			Cu, 0.70 min					
Reason for Change:														
Continuity of supply.														
					ology	trend	ds and u	se wiring	with enha	nced	d mech	anical	and	
		ical prop												
		nize flexi easier to					nbly/Tes	t product	ion sites.					
5)	Cuis	easier to	obla	in anu	SLUCK									
Anticipated impact on Form, Fit, Function, Quality or Reliability (positive / negative):														
Nor	None													
Anticipated impact on Material Declaration														
		mpact to							Product Co					
	Material Declaration production data and will be available following the product													
								ease the revised reports can be						
Ch	obtained from the <u>TI ECO website</u> . Changes to product identification resulting from this PCN:													
		to proc	iuct i	aenti	ricatio	on re	esuiting	from th	IS PCN:					
Nor	ne													

Product Affected:					
		TH000000000000000000000000000000000000	TH000000000000000		
DM365ZCES	TMS320DM361ZCE	TMS320DM367ZCE30	TMS320DM368ZCEG		
DM365ZCEW	TMS320DM362ZCE	TMS320DM367ZCED	TMS320DM369ZCE		
DM365ZCEZ	TMS320DM362ZCE30	TMS320DM367ZCED30	TMS320DM369ZCED		
DM368ZCEDZ	TMS320DM365ZCE	TMS320DM367ZCEF	TMS320DM369ZCEDF		
DM368ZCEZ	TMS320DM365ZCE21	TMS320DM368GZCEF	TMS320DM369ZCEF		
DMVA1ZCE	TMS320DM365ZCE27	TMS320DM368ZCE	VCBU65WMCE30		
DMVA1ZCED	TMS320DM365ZCE30	TMS320DM368ZCE48	VCBU68WMCE30		
DMVA25ZCE	TMS320DM365ZCED30	TMS320DM368ZCED	VS3673UNION		
DMVA2ZCE	TMS320DM365ZCEF	TMS320DM368ZCED48F	VS3674PITTA		
DMVA2ZCED	TMS320DM365ZCEZ	TMS320DM368ZCEDF	VS3674UNION		
DMVA2ZCEDR	TMS320DM367ZCE	TMS320DM368ZCEF	VVLOG365ZCE		
DMVA2ZCER					



TI Information Selective Disclosure

Qualification Report

0.70mil Cu Qual - Freon 361ZWT nfBGA driver Approve Date 08-Jun-2015

Product Attributes

Attributes	Qual Device: TMS320C6748BZWTA3E	QBS Product Reference: 771570ZCE365	QBS Package Reference: TNETV1061ZWC	
Assembly Site	PHI (TIPI)	PHI (TIPI)	PHI (TIPI)	
Package Family	NFBGA	NFBGA	NFBGA	
Wafer Fab Supplier	UMC FAB12I	UMCI	DMOS6	
Wafer Fab Process	1218C021.M6	1218C021.M7	1533C035.15C2	

- QBS: Qual By Similarity
- Qual Device TMS320C6748BZWTA3E is qualified at LEVEL3-260CG

Qualification Results Data Displayed as: Number of lots / Total sample size / Total failed

Туре	Test Name / Condition	Duration	Qual Device: TMS320C6748BZWTA3E	QBS Product Reference: 771570ZCE365	QBS Package Reference: TNETV1061ZWC	
PC	PreCon Level 3	3XIR/260C	3/960/0	3/870/0	-	
PC	PreCon Level 4	3XIR/260C	-	-	3/1080/0	
HTOL	Life Test, 125C	1000hrs/125C	-	3/240/0	3/240/0	
THB	Biased Temperature and Humidity, 85C/85%RH	1000hrs/85C/85%RH	3/78/0	-	-	
UHAST	Unbiased HAST 110C/85%RH	264hrs/110C/85%RH	3/240/0	3/240/0	3/300/0	
TC	Temperature Cycle, -55/125C	1000cyc/-55C/125C	3/240/0	3/240/0	3/240/0	
HTSL	High Temp Storage Bake 150C	1000hrs/150C	3/240/0	3/300/0	3/179/0	
WBP	Bond Strength	76 ball bonds, min. 3 units	3/Pass	-	3/228/0	
MQ	Manufacturability (Assembly)	(per mfg. Site specification)	3/Pass	3/Pass	3/Pass	
PD	Physical Dimensions (per mechanical drawing)		-	-	1/10/0	
YLD	FTY and Bin Summary	-	3/Pass	-	3/Pass	

- Preconditioning was performed for Autoclave, Unbiased HAST, THB/Biased HAST, Temperature Cycle, Thermal Shock, and HTSL, as applicable

- The following are equivalent HTOL options based on an activation energy of 0.7eV : 125C/1k Hours, 140C/480 Hours, 150C/300 Hours, and 155C/240 Hours

155C/240 Hours

- The following are equivalent HTSL options based on an activation energy of 0.7eV : 150C/1k Hours, and 170C/420 Hours

- The following are equivalent Temp Cycle options per JESD47 : -55C/125C/700 Cycles and -65C/150C/500 Cycles

Quality and Environmental data is available at TI's external Web site: http://www.ti.com/

Green/Pb-free Status:

Qualified Pb-Free(SMT) and Green

For questions regarding this notice, e-mails can be sent to the regional contacts shown below or your local Field Sales Representative.

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